R.1.A.990106-HERIC



1617-35

35 Watts, 28 Volts, Pulsed Radar 1540 - 1660 MHz

ADVANCED ISSUE

GENERAL DESCRIPTION

The 1617-35 is a high power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 1540 - 1660 MHz. The transistor includes input and output prematch for broadband performance. The device has gold thin-film metallization and diffused ballasting for proven highest MTTF. Low thermal resistance Solder Sealed Package reduces junction temperature, extends life.

CASE OUTLINE 55AT

ABSOLUTE MAXIMUM RATINGS

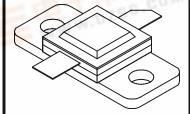
Maximum Power Dissipation

Device Dissipation @25°C 290 W

Maximum Voltage and Current

Collector to Base Voltage (BVces) 50 V 3.0 V Emitter to Base Voltage (BV_{ebo}) Maximum Temperatures
Storage Town

Storage Temperature -65 to +200 °C Operating Junction Temperature +200 °C



ELECTRICAL CHARACTERISTICS @ 25°C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
P _{out}	Power Out	F = 1660 MHz	35			W
P _{in}	Power Input	Vcc = 28 Volts			6	W
P_{g}	Power Gain	PW = Note 1	7.6			dB
η_c	Collector Efficiency	DF = Note 1		50		%
VSWR	Load Mismatch Tolerance	F = 1540 MHz			10:1	

FUNCTIONAL CHARACTERISTICS @ 25°C

$\mathrm{BV}_{\mathrm{ebo}}$	Emitter to Base Breakdown	Ie = 20 mA	3.0	271	V.	V
$\mathrm{BV}_{\mathrm{ces}}$	Collector to Emitter Breakdown	Ic = 60 mA	50	THE WAY	Mrs.	V
h_{FE}	DC – Current Gain	Vce = 5V, Ic = 500mA	20			
θjc^2	Thermal Resistance				0.6	°C/W

NOTE 1: 5 µs at 15% Duty

WWW.DZSC.COM 2. At rated pulse conditions